SQ4410EY

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Vishay Siliconix

Automotive N-Channel 30 V (D-S) 175 °C MOSFET



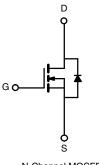
PRODUCT SUMMARY				
V _{DS} (V)	30			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.012			
$R_{DS(on)}$ (Ω) at V_{GS} = 4.5 V	0.020			
I _D (A)	15			
Configuration	Single			

FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



COMPLIANT HALOGEN



N-Channel MOSFET

ORDERING INFORMATION				
Package	SO-8			
Lead (Pb)-free and halogen-free	SQ4410EY (for detailed order number please see <u>www.vishay.com/doc?79771</u>)			

ABSOLUTE MAXIMUM RATINGS ($T_C = 25 \degree C$, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	30	V	
Gate-source voltage		V _{GS}	± 20	v	
Continuous drain current	T _C = 25 °C	1	15		
	T _C = 125 °C	I _D	9		
Continuous source current (diode conduction)		۱ _S	4.5	А	
Pulsed drain current ^a		I _{DM}	60		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	38		
Single pulse avalanche energy		E _{AS}	72	mJ	
Maximum power dissipation ^a	T _C = 25 °C	- P _D	5	W	
	T _C = 125 °C		1.6	vv	
Operating junction and storage temperature rat	nge	T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount ^b	R _{thJA}	90	°C/W	
Junction-to-foot (drain)		R _{thJF}	30		

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. When mounted on 1" square PCB (FR4 material)

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SQ4410EY



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SPECIFICATIONS (T _C = 25 °C PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT	
Static							
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0, I _D = 250 μA		30	-	-	v
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μΑ	1.5	2.0	2.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 30 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 30 V, T _J = 125 °C	-	-	50	μA
		$V_{GS} = 0 V$	V _{DS} = 30 V, T _J = 175 °C	-	-	150	
On-state drain current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	20	-	-	Α
		$V_{GS} = 10 V$	I _D = 10 A	-	0.009	0.012	
Ducin actures on state registeries a	Б	$V_{GS} = 10 V$	I _D = 6 A, T _J = 125 °C	-	-	0.018	Ω
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 6 A, T _J = 175 °C	-	-	0.021	
		$V_{GS} = 4.5 V$	I _D = 5 A	-	0.015	0.020	
Forward transconductance b	g fs	V _{DS}	= 15 V, I _D = 10 A	-	34	-	S
Dynamic ^b		<u>.</u>					
Input capacitance	C _{iss}		_S = 0 V V _{DS} = 25 V, f = 1 MHz	-	1906	2385	pF
Output capacitance	C _{oss}	$V_{GS} = 0 V$		-	460	575	
Reverse transfer capacitance	C _{rss}			-	183	230	
Total gate charge ^c	Qg			-	35	53	
Gate-source charge ^c	Q _{gs}	$V_{GS} = 10 V$	$V_{DS} = 15 \text{ V}, I_D = 10 \text{ A}$	-	4.9	-	nC
Gate-drain charge ^c	Q _{gd}			-	5.4	-	
Gate resistance	R _g	f = 1 MHz		0.5	-	2	Ω
Turn-on delay time ^c	t _{d(on)}		V _{DD} = 15 V, R _I = 1.5 Ω		11	17	
Rise time ^c	t _r	V _{DD} =			7	11	ns
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 10$ Å, $V_{GEN} = 10$ V, $R_g = 1$ Ω		-	29	44	
Fall time ^c	t _f			-	8	12	1
Source-Drain Diode Ratings and Chai	acteristics ^b						
Pulsed current ^a	I _{SM}	1		-	-	60	Α
Forward voltage	V _{SD}	IF :	-	0.72	1.2	V	

Notes

c. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%$

d. Guaranteed by design, not subject to production testing

e. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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- 55 °C

5

Г_С

4

 $T_C = -55 \ ^\circ C$

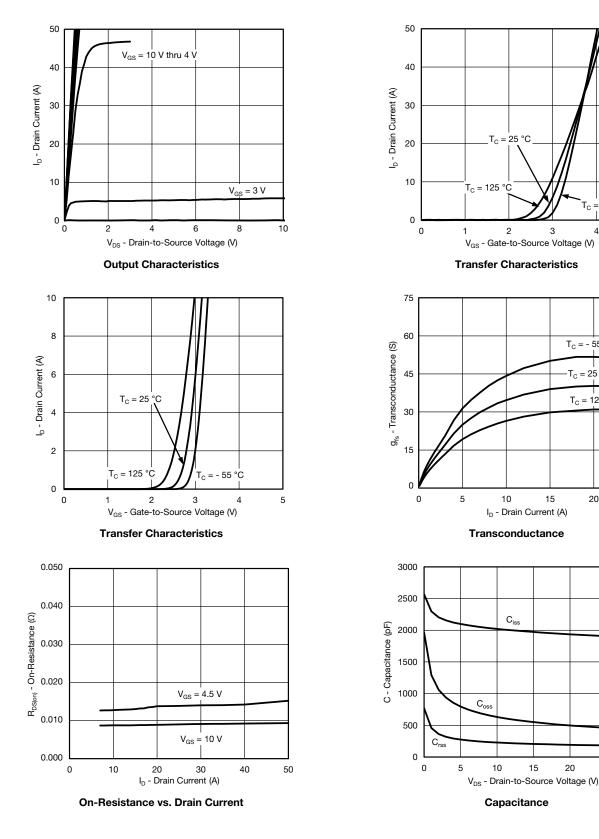
T_C = 25 °C

T_C = 125 °C

20

25

TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)





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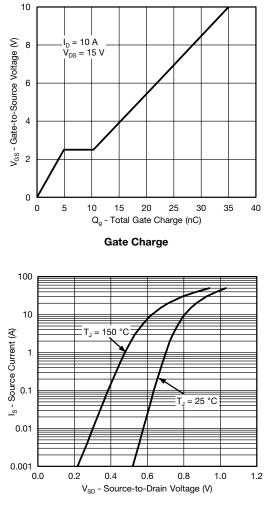
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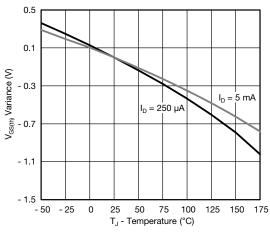
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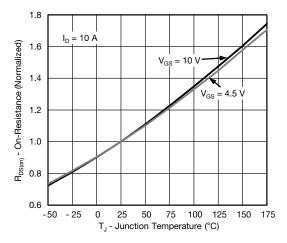
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



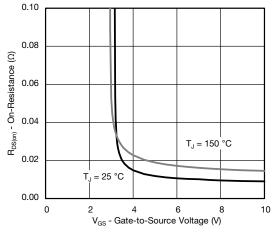
Source Drain Diode Forward Voltage



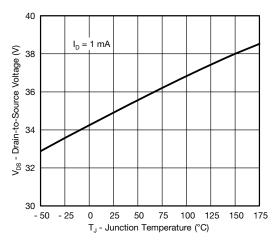
Threshold Voltage



On-Resistance vs. Junction Temperature







Drain Source Breakdown vs. Junction Temperature

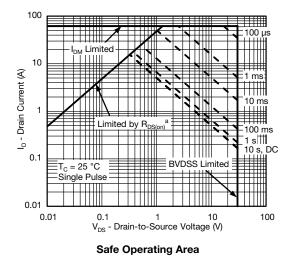
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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)

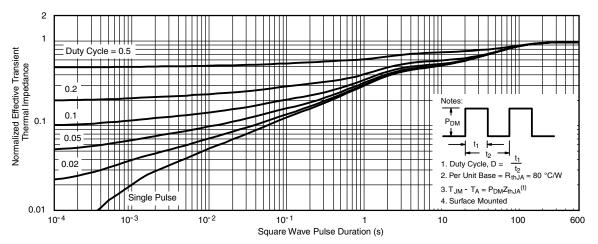


Note

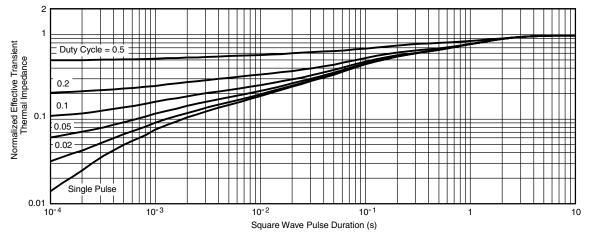
a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified



THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to Foot

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?65674.

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Package Information

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SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





	MILLIMETERS		INC	CHES	
DIM	Min	Мах	Min	Max	
A	1.35	1.75	0.053	0.069	
A ₁	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
E	3.80	4.00	0.150	0.157	
е	1.27 BSC		0.050 BSC		
н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	
S	0.44	0.64	0.018	0.026	
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498					

Application Note 826

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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